



# Product data sheet

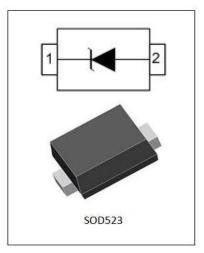
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## Features

- ♦ 150 Watts peak pulse power (tp = 8/20µs)
- Transient protection for high speed data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns)
- Working voltages : 12V
- Protects One Power or I/O Port
- Low operating and clamping voltages
- Solid-state silicon avalanche technology



# Applications

- Notebooks, Desktops, Servers and Video Graphics Cards
- USB Power & Data Line Protection
- Monitors and Flat Panel Displays
- I<sup>2</sup>C Bus Protection
- Portable Instrumentation
- Set Top Box

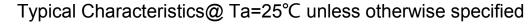
## Electrical Characteristics@ Ta=25°C unless otherwise

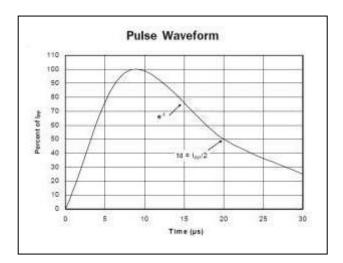
	Vrwm@Ir		Vbr@lmA	Vc@1	VC@IPP		Сј
P/N	V	μA	V	V	V	А	pF
		MAX	MIN	MAX	MAX		MAX
PESD12VS1UB	12	1	13.3	19	25	6	70

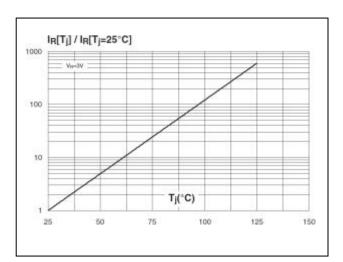
# Maximum Rating @ Ta=25°C unless otherwise specified

Symbol	Parameter	Ratings	Units
Ррк	Peak Pulse Power (tp = 8/20µs)	150	Watts
Τι	Lead Soldering Temperature	260(10sec.)	°C
TJ	Operating Temperature	-55 to +125	°C
Тѕтс	Storage Temperature	-55 to +150	°C

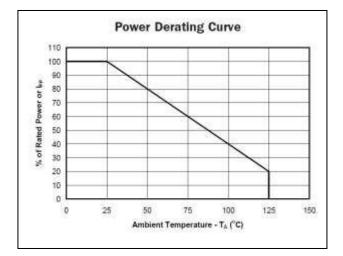








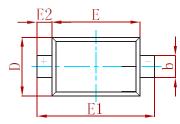
# Non-Repetitive Peak Pulse Power vs. Pulse Time

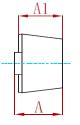


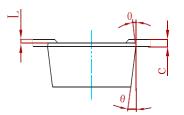




## PACKAGE MECHANICAL DATA

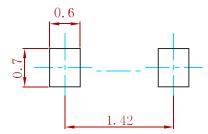






Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
A	0.510	0.770	0.020	0.031	
A1	0.500	0.700	0.020	0.028	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	0.750	0.850	0.030	0.033	
E	1.100	1.300	0.043	0.051	
E1	1.500	1.700	0.059	0.067	
E2	0.200	REF	0.008 REF		
L	0.010	0.070	0.001	0.003	
0	7° F	REF	7° REF		

# Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.

3. The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
PESD12VS1UB-MS	SOD-523	3000





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